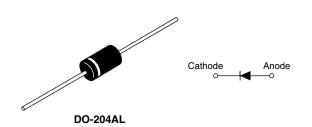


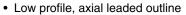
Vishay High Power Products

Schottky Rectifier, 1 A



PRODUCT SUMMARY			
I _{F(AV)}	1 A		
V _R	100 V		

FEATURES







- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- · Lead (Pb)-free plating
- Designed and qualified for industrial level

DESCRIPTION

The MBR1100 axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	A		
V _{RRM}		100	V		
I _{FSM}	$t_p = 5 \mu s sine$	200	A		
V _F	1 Apk, T _J = 125 °C	0.68	V		
T _J	Range	- 40 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	MBR1100	UNITS	
Maximum DC reverse voltage	V_{R}	100	V	
Maximum working peak reverse voltage	V_{RWM}	100	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T _C = 85 °C, rectangular waveform		10	
Maximum peak one cycle non-repetitive surge current	leo	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	200	Α
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse		50	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by, T _J maximum V _A = 1.5 x V _R typical		0.5	Α

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.85	V
		2 A		0.96	
See fig. 1		1 A	T _J = 125 °C	0.68	
		2 A		0.78	
Maximum reverse leakage current	imum reverse leakage current	T _J = 25 °C	V _R = Rated V _R	0.5	mA
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C		1.0	IIIA
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz) 25 °C		35	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to lead	R _{thJL} (2)	DC operation See fig. 4	80	°C/W
Approximate weight			0.33	g
		0.012	oz.	
Marking device		Case style DO-204AL (DO-41) (JEDEC)	MBR	1100

Notes

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⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

⁽²⁾ Mounted 1" square PCB, thermal probe connected to lead 2 mm from package



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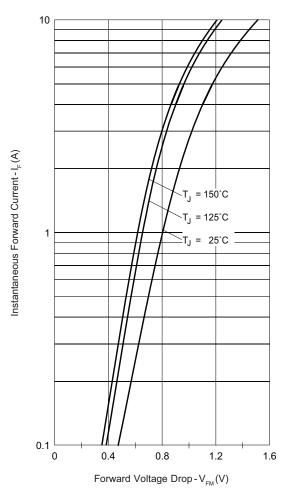


Fig. 1 - Maximum Forward Voltage Drop Characteristics

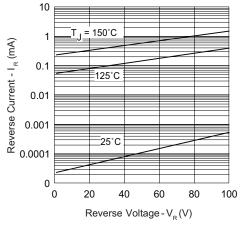


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

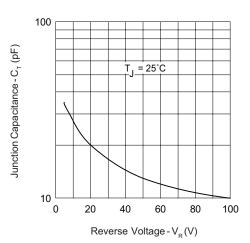


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

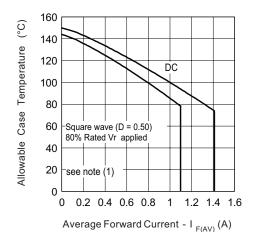


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

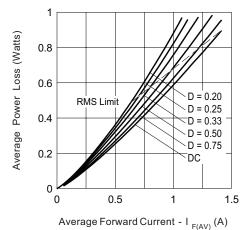


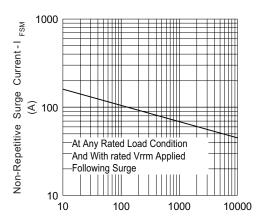
Fig. 5 - Forward Power Loss Characteristics

Note

 $^{(1)} \text{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6); } Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_{R} \text{ (1 - D); } I_{R} \text{ at } V_{R1} = 80 \text{ \% rated } V_{R1} \text{ (1 - D); } I_{R} \text{ (1 - D); } I$

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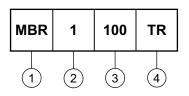


Square Wave Pulse Duration - t_p (microsec)

Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE

Device code



1 - Schottky MBR series

2 - Current rating: 1 = 1 A

3 - Voltage rating: 100 = 100 V

- TR = Tape and reel package (5000 pcs)

None = Box package (1000 pcs)

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95241			
Part marking information	http://www.vishay.com/doc?95304		
Packaging information	http://www.vishay.com/doc?95308		



Vishay

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